



25V PNP HIGH PERFORMANCE TRANSISTOR IN POWERDI3333-8

Features

- BV_{CEO} > -25V
- Small Form Factor Thermally Efficient Package. Enables Higher Density End Products
- I_C = -3A High Continuous Current
- I_{CM} = -8A Peak Pulse Current
- Low Saturation Voltage VCE(sat) < -200mV @ -1A
- Complementary NPN Type: DXTN07025BFG
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.03 grams (Approximate)

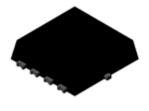
Applications

- High-Side Switch
- Low Drop Out Regulator
- MOSFET or IGBT Gate Driving

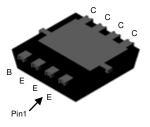
PowerDI3333-8 (SWP) (Type UX)



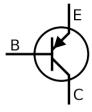








Bottom View



Device Symbol

Ordering Information (Notes 4)

•						
	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	DXTP07025BFG-7	AFC-Q101	2H9	7	12	2000

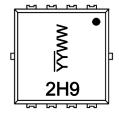
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- <1000ppm antimony compounds.

 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2H9= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 18 = 2018)

WW = Week Code (01 to 53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-35	V
Collector-Emitter Voltage	V _{CEO}	-25	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-3	Α
Peak Pulse Current	I _{CM}	-8	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		0.9	W
Power Dissipation	(Note 6)	P_{D}	2.1	W
	(Note 7)]	3.1	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8	ReJL	8.5	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

Notes:

- 1. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
- 2. Same as Note 5, except the device is mounted on 25mm × 25mm 2oz copper.

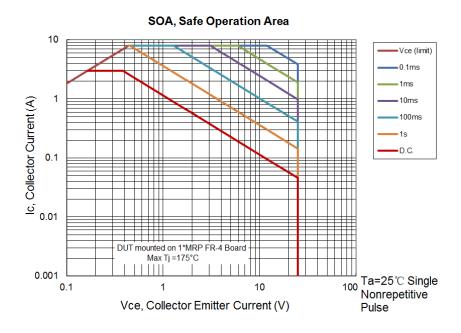
 3. Same as Note 5, except the device is mounted on 50mm × 50mm 2oz copper.

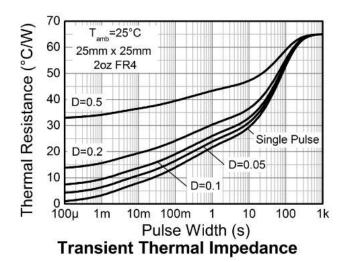
 4. Thermal resistance from junction to solder-point (at the collector tab).

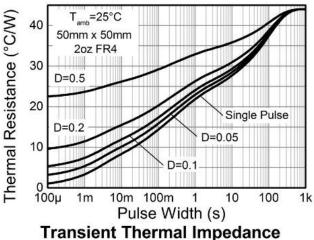
 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

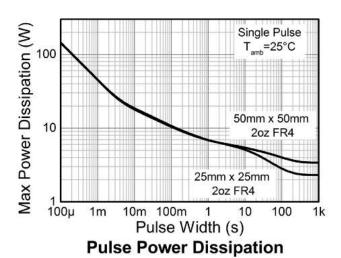


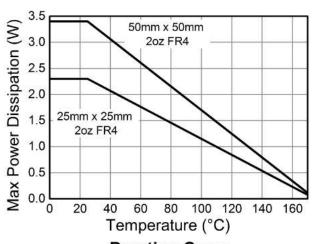
Thermal Characteristics and Derating Information













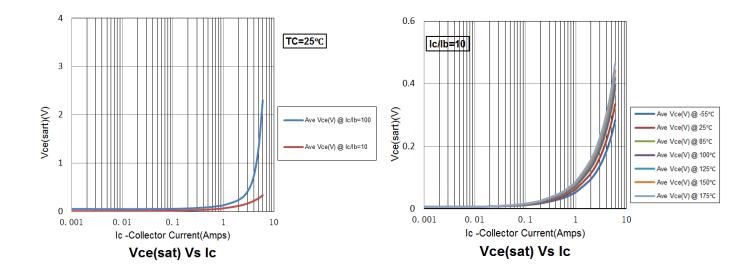
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

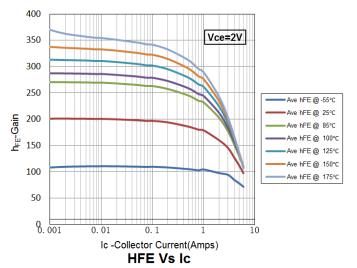
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-35	-71	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-25	-42	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.3	_	V	$I_E = -100 \mu A$
Collector Cut-Off Current		_	_	-20	nA	V _{CB} = -30V
Collector Gut-On Gurrent	I _{CBO}	_	_	-10	μΑ	V _{CB} = -30V, T _A = +125°C
Emitter Cut-Off Current	I _{EBO}	_	_	-20	nA	V _{EB} = -6V
Collector Frontier Cotton Volton (Note 10)	M	_	-64	-200	mV	I _C = -1A, I _B = -100mA
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(SAT)}$	_	-164	-400	mV	I _C = -3A, I _B = -300mA
Base-Emitter Saturation Voltage (Note 10)	V _{CE(SAT)}	_	-0.86	-1	V	I _C = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 10)	$V_{BE(ON)}$	_	-0.77	-0.9	V	I _C = -1A, V _{CE} = -2V
	h _{FE}	70	196	_	_	I _C = -50mA, V _{CE} = -2V
DC Current Coin (Note 10)		100	174	300	_	I _C = -1A, V _{CE} = -2V
DC Current Gain (Note 10)		75	153	_	_	I _C = -2A, V _{CE} = -2V
		40	94	_	_	I _C = -6A, V _{CE} = -2V
Current Gain-Bandwidth Product	f _T	100	160	_	MHz	V _{CE} = -5V, I _C = -100mA f = 100MHz
Turn-On Time	t _{on}	_	40	_	ns	V _{CC} = -10V, I _C = -500mA
Turn-Off Time	t _{off}	_	450	_	ns	$I_{B1} = -I_{B2} = -50mA$
Output Capacitance	C_{obo}	_	55	100	pF	$V_{CB} = -10V$, $f = 1MHz$

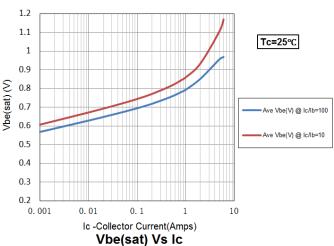
Note: 10. Measured under pulsed conditions. Pulse width $\leq 300~\mu$ s. Duty cycle $\leq 2\%$.

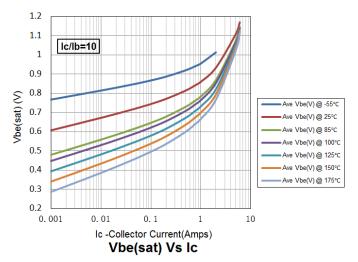


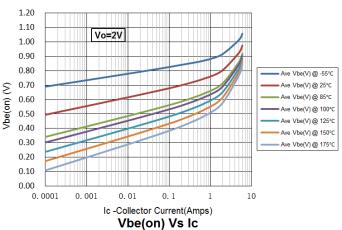
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









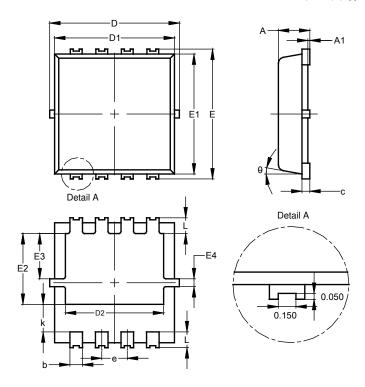




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

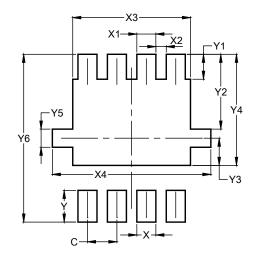


PowerDI3333-8 (SWP)						
(Type UX) ´						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	_			
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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